

**INTERNATIONAL CENTRE FOR APPLIED SCIENCES**

(Manipal University)

**IV SEMESTER B.S. DEGREE EXAMINATION – MAY 2016**

**SUBJECT: ELECTRONIC DEVICES AND COMPUTER INTERFACING (CS -241)**

**(NEW SCHEME)**

**20<sup>TH</sup> MAY, 2016**

**Time: 3 Hours**

**Max. Marks: 100**

- ✓ **Answer ANY FIVE full Questions.**
- ✓ **Missing data may be suitably assumed.**

- 1A. Explain with circuit diagram the working of PN junction diode along with diode current equation and its V-I characteristics under different bias conditions.
- 1B. Explain a series and parallel clipper circuit with circuit diagram.
- 1C. A Si diode has reverse saturation current 13 nA at 20°C. (a) Find the diode current when it is forward biased by 0.7 V. (b) Find the diode current when the temperature rises to 125°C. (8+6+6)
- 2A. Describe a square wave generator using OPAMP.
- 2B. Determine  $V_O$  for the network shown in Fig Q2B., for the input indicated. Show the steps involved. (10+10)
- 3A. Describe with a neat circuit diagram, explain the RC coupled amplifier and its frequency response.
- 3B. Explain the construction, working and characteristics of enhancement MOSFET. Sketch drain and transfer characteristics.
- 3C. In a transistor, 99% of the carriers injected into the base cross over to the collector region. If collector current is 4mA and collector leakage current is 6  $\mu$ A, calculate emitter and base currents. (8+8+4)
- 4A. A Zener voltage regulator provides a load current of 20mA when connected to an input of 10V supply. If  $V_Z = 5V$  and  $R_S = 100 \Omega$ , calculate the load resistance  $R_L$ , current through Zener diode  $I_Z$  and the current drawn from the supply.
- 4B. For the circuit shown in Fig Q4B, determine  $I_{BQ}$ ,  $I_{CQ}$ ,  $V_{CEQ}$ ,  $V_C$ ,  $V_E$ ,  $V_B$ . (10+10)
- 5A. Explain with neat internal block diagram how 555 timer can be used as monostable multi vibrator with necessary waveform.
- 5B. Explain successive approximation type of ADC with neat block diagram. (10+10)
- 6A. An AC voltage of 230V, 50Hz is applied to transformer having turns ratio 10:1. The secondary of transformer is connected to half wave rectifier. The diode has cut-in voltage 0.6V and forward resistance 10 $\Omega$ . Determine average and rms values of output current and voltage. What is the PIV rating of the diode? Assume load resistance of 1 k $\Omega$ .

6B. Write a general data acquisition system block diagram and explain functions of these blocks.

(10+10)

7A. Explain all the ideal characteristics and parameters of OPAMP.

7B. Explain with neat circuit diagram how TRIAC can be used as a full wave rectifier. How the output power is controlled?

7C. What is Barkhausen criteria? Write the circuit of Hartley oscillator and explain its working.

(6+7+7)

8A. Explain the working of DIAC with the characteristics and mention its applications.

8B. Write notes on: Varactor diode and photo diode.

8C. Explain the two breakdown mechanism in PN junction diode with diagram

(6+8+6)

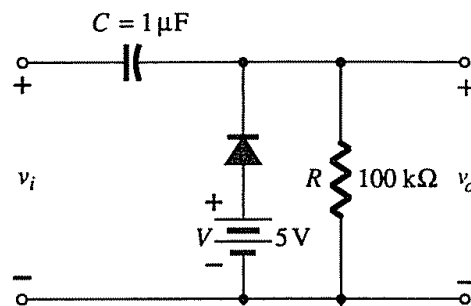
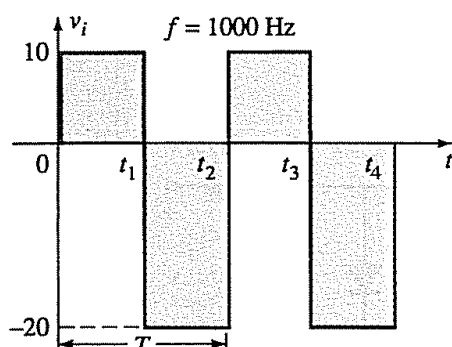


Fig Q2B.

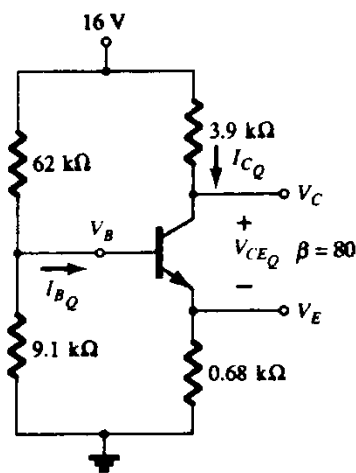


Fig.Q.4B

